



GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

Typical Applications

The HMC6147ALC5A is ideal for:

- Point-to-Point and Point-to-Multi-Point Radio
- Military Radar, EW & ELINT
- Satellite Communications
- Sensors

Features

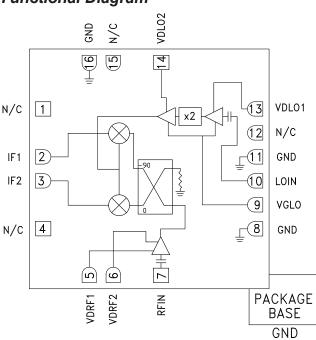
Conversion Gain: 13 dB

Excellent Image Rejection: 25 dB

Output IP3: +12 dBm

16 Lead 5x5 mm SMT Ceramic Package: 25 mm²

Functional Diagram



General Description

The HMC6147ALC5A is a compact GaAs MMIC I/Q downconverter in a leadless RoHS compliant SMT package. This device provides a small signal conversion gain of 13 dB with 25 dBc of sideband rejection. The HMC6147ALC5A utilizes a low noise amplifier to drive the I/Q mixer where the LO is driven by a X2 multiplier. IF1 and IF2 mixer inputs are provided and an external 90° hybrid is needed to select the required sideband. The I/Q mixer topology reduces the need for filtering of the unwanted sideband. The HMC6147ALC5A is a much smaller alternative to hybrid style single sideband converter assemblies and it eliminates the need for wire bonding by allowing the use of surface mount manufacturing techniques.

Electrical Specifications ^{[1][2]}, $T_A = +25^{\circ}\text{C}$, IF = 1000 MHz, LO = +3 dBm, VDLO1,2 = +3V, IDLO1,2 = 150 mA, VDRF1,2 = +3V, IDRF1,2 = 75 mA, USB ^{[1][2]}

Parameter	Min.	Тур.	Max.	Units
Frequency Range, RF		GHz		
Frequency Range, LO		16.5 - 22		GHz
Frequency Range, IF		0 - 4		GHz
Conversion Gain	10	13		dB
Image Rejection	15	25		dBc
1 dB Compression (Output)		1		dBm
IP3 (Input)		2		dBm
Noise Figure		3.5		dB
Supply Current IDLO1 + IDLO2 quiescent [2]		150		mA
Supply Current IDRF1 + IDRF2		75		mA

^[1] Unless otherwise noted all measurements performed with low side LO, IF = 1000 MHz and external IF 90° hybrid.

^[2] Adjust Vgg between -2 to 0V to achieve IDLO1 + IDLO2 = 150 mA Typical with RF turned off.

HMC6147A* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS -

View a parametric search of comparable parts.

EVALUATION KITS

· HMC6147ALC5A Evaluation Board

DOCUMENTATION

Data Sheet

• HMC6147A Data Sheet

REFERENCE MATERIALS 🖵

Quality Documentation

 Package/Assembly Qualification Test Report: LC5, LC5A (QTR: 2014-00384 REV: 01)

Technical Articles

 The Changing Landscape of Frequency Mixing Components

DESIGN RESOURCES 🖵

- HMC6147A Material Declaration
- PCN-PDN Information
- · Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC6147A EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK 🖳

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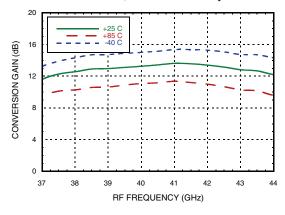




GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

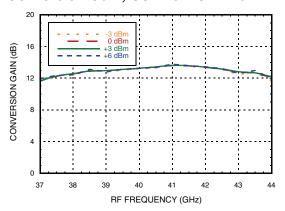
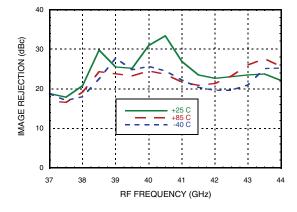
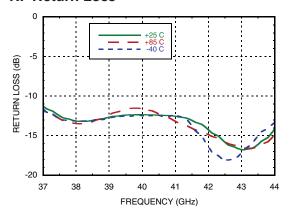


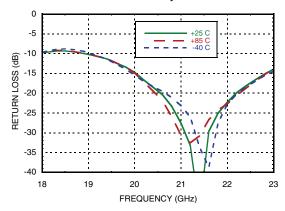
Image Rejection vs. Temperature



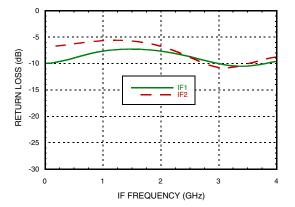
RF Return Loss



LO Return Loss vs. Temperature



IF Return Loss [1]



[1] Data taken without external IF 90° hybrid

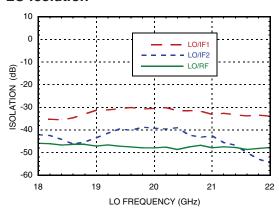




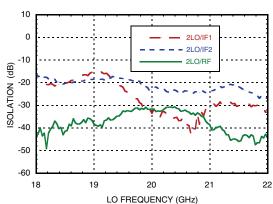
GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

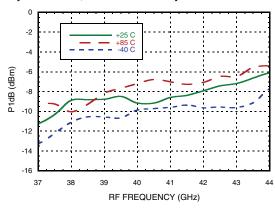
LO Isolation



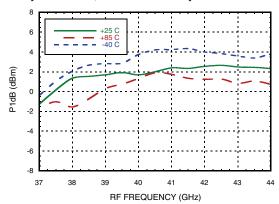
2LO Isolation



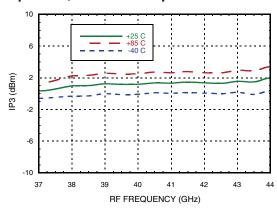
Input P1dB, USB vs. Temperature



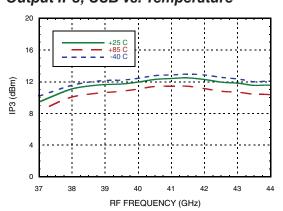
Output P1dB, USB vs. Temperature



Input IP3, USB vs. Temperature



Output IP3, USB vs. Temperature



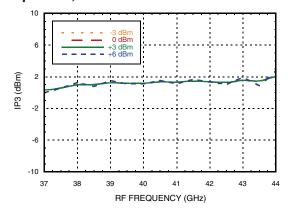




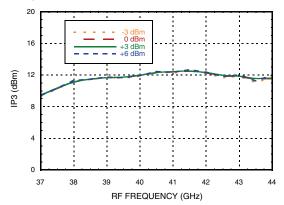
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Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 1000 MHz

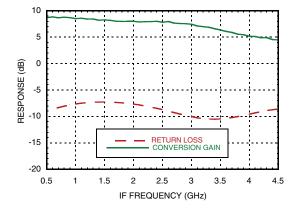
Input IP3, USB vs. LO Power



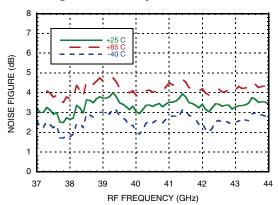
Output IP3, USB vs. LO Power



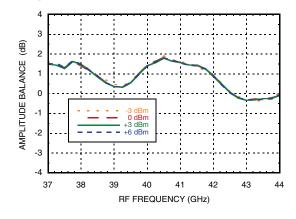
IF Bandwidth [1]



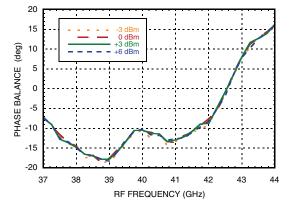
Noise Figure vs. Temperature



Amplitude Balance vs. LO Drive



Phase Balance vs. LO Drive



[1] LO = 18GHz

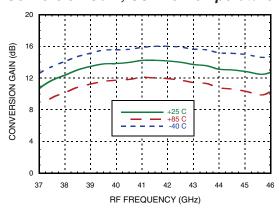




GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 2000 MHz

Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

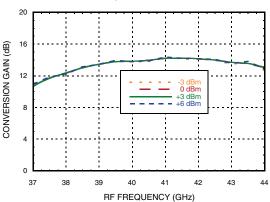
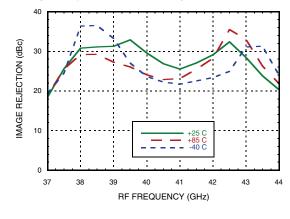
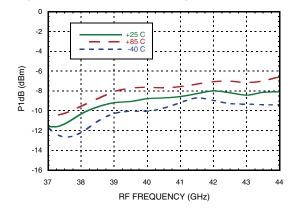


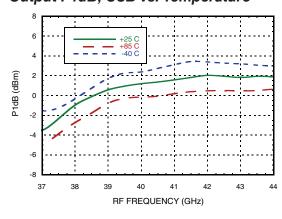
Image Rejection vs. Temperature



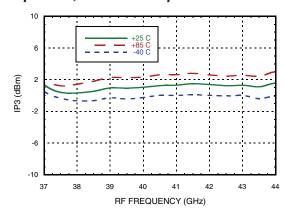
Input P1dB, USB vs. Temperature



Output P1dB, USB vs. Temperature



Input IP3, USB vs. Temperature



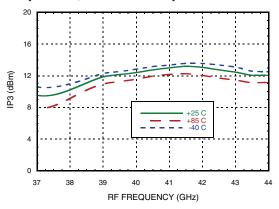




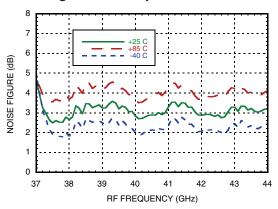
GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 2000 MHz

Output IP3, USB vs. Temperature



Noise Figure vs. Temperature



MxN Spurious Outputs [1][2]

	nLO				
mRF	0	1	2	3	4
0	xx	38	21		
1	17	48	0		
2	xx	xx	47		
3					
4					
5					

RF = 40 GHz @ -8 dBm LO = 19.5 GHz @ +4 dBm

MxN Spurious Outputs [1][2]

	nLO				
mRF	0	1	2	3	4
0	xx	42	16		
1	17	47	0		
2	xx	xx	43		
3					
4					
5					

RF = 40 GHz @ -8 dBm LO = 19.0 GHz @ +4 dBm

MxN Spurious Outputs [1][2]

	nLO				
mRF	0	1	2	3	4
0	xx	44	20		
1	17	41	0		
2	xx	xx	50		
3					
4					
5					

RF = 40 GHz @ -8 dBm LO = 18.5 GHz @ +4 dBm

^[1] Data taken without external IF 90° hybrid

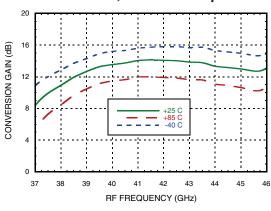
^[2] All values in dBc below RF power level (2LO + IF) USB

RoHS√

GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 3000 MHz

Conversion Gain, USB vs. Temperature



Conversion Gain, USB vs. LO Drive

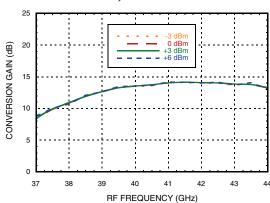
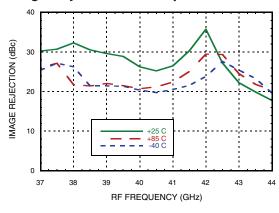
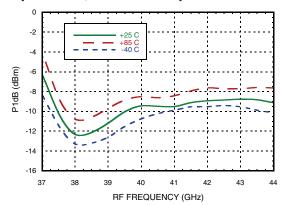


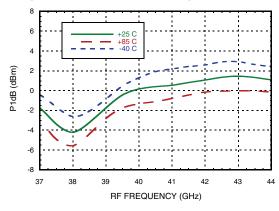
Image Rejection vs. Temperature



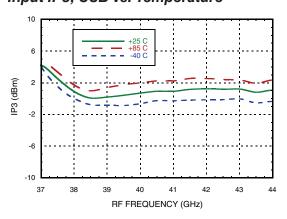
Input P1dB, USB vs. Temperature



Output P1dB, USB vs. Temperature



Input IP3, USB vs. Temperature



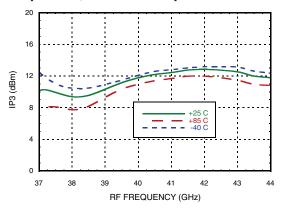




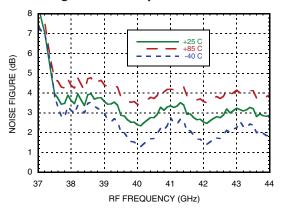
GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

Data Taken as SSB Downconverter with External IF 90° Hybrid, IF = 3000 MHz

Output IP3, USB vs. Temperature



Noise Figure vs. Temperature







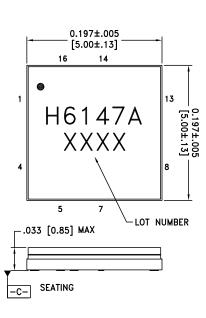
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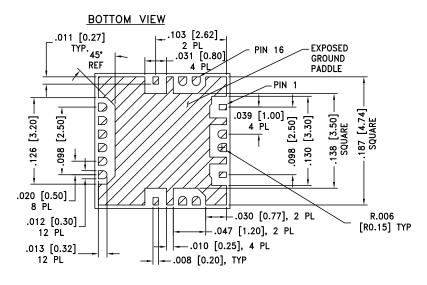
Absolute Maximum Ratings

RF Input	+8 dBm
LO Input	+10 dBm
Bias Voltage, VDLO and VDRF	+3.5V
Channel Temperature	175 °C
Continuous Pdiss (T = 85°C) (derate 17.8 mW/°C above 85°C)	1.6 W
Thermal Resistance (channel to ground paddle)	56 °C/W
Storage Temperature	-65 to +150 °C
Operating Temperature	-40 to +85 °C
ESD Sensitivity (HBM)	Class1A



Outline Drawing





NOTES:

- 1. PACKAGE BODY MATERIAL: ALUMINA
- LEAD AND GROUND PADDLE PLATING: 30 80 MICROINCHES GOLD OVER 50 MICROINCHES MINIMUM NICKLE
- 3. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 4. LEAD SPACING TOLERANCE IS NON-CUMULATIVE
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm DATUM
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND

Package Information

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [2]
HMC6147ALC5A	Alumina, White	Gold over Nickel	MSL3 ^[1]	6147A XXXX

^[1] Max peak reflow temperature of 260 °C

^{[2] 4-}Digit lot number XXXX





GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

Pin Descriptions

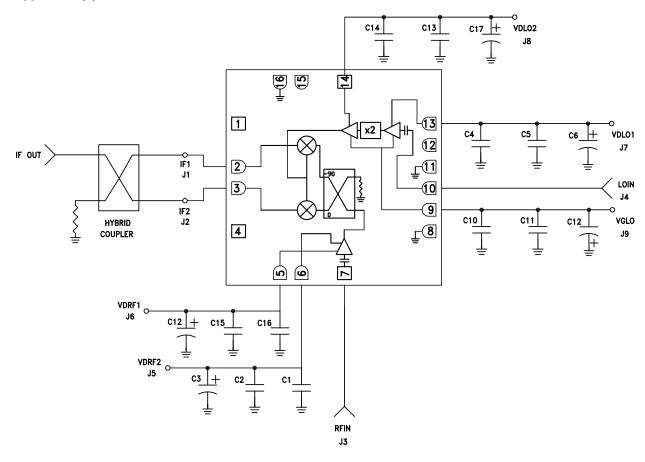
Pin Number	Function	Description	Interface Schematic
1, 4, 12,15	N/C	No connection required. The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
2	IF1	These pins are DC coupled. For applications not requiring operation to DC this port should be DC blocked externally using a series capacitor whose value has been chosen to	IF1,IF2 0—
3	IF2	pass the necessary frequency range. For operation to DC, this pin must not sink / source more than 3 mA of current or part non-function and possible failure will result.	¥ <u>‡</u>
5	VDRF1	Di C INA TI	OVDRF1, VDRF2
6	VDRF2	Bias for LNA. The recommended DC voltage is 3V	
7	RFIN	This pin is AC coupled and matched to 50 Ohms.	RFIN ○── ├──
8,11, 16	GND	These pins and expossed ground paddle must be connected to RF/DC ground.	♥ GND =
9	VG	Adjust VGLO for -1V to 0V to set the multiplier quiescent current to 150mA	VG =
10	LOIN	LO Input Port. The recommended LO Power is 0 to 6 dBM	LOIN 0
13	VDLO1	Bias for Multiplier input Buffer Amp. The recommended DC voltage is 3V	OVDLO1, VDLO2
14	VDLO2	Bias for Multiplier output Buffer Amp. The recommended DC voltage is 3V	





GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

Typical Application



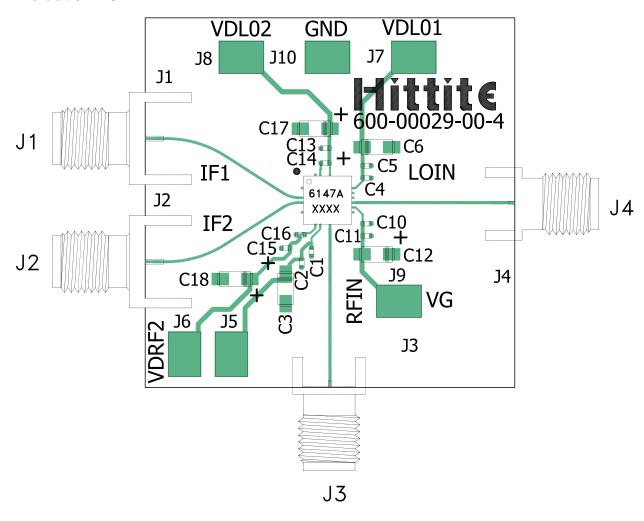
C1, C4, C10, C14, C16	100 pF Capacitor, 0402 Pkg.
C2, C5, C11, C13, C15	0.1uF Capacitor, 0402 Pkg.
C3, C6, C12, C17, C19	4.7 μF Capacitor, Case A Pkg.





GaAs MMIC I/Q DOWNCONVERTER 37 - 44 GHz

Evaluation PCB



List of Materials for Evaluation PCB Eval01-HMC6147ALC5A [1]

Item	Description
J1, J2	SMA Connector
J3, J4	K-Connector SRI
J5 - J10	DC Pins
C1, C4, C10, C14, C16	100 pF Capacitor, 0402 Pkg.
C2, C5, C11, C13, C15	0.1 uF Capacitor, 0402 Pkg.
C3, C6, C12, C17, C18	4.7 μF Capacitor, Case A
U1	HMC6147ALC5A Downconverter
PCB [2]	600-00029-00 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB

[2] Circuit Board Material: Arlon 25FR, FR4 or Rogers 4350

The circuit board used in the application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.